

# 2MBI75VA-120-50

**IGBT Modules** 

# **IGBT MODULE (V series)** 1200V / 75A / 2 in one package

#### Features

High speed switching Voltage drive Low Inductance module structure

#### Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines

### Maximum Ratings and Characteristics

# ● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items	Symbols	Conditions	Conditions		Units	
Collector-Emitter voltage	VCES			1200	V	
Gate-Emitter voltage	Vges				V	
Collector current	lc	Continuous	Tc=100°C	75		
	C pulse	1ms	1ms 1ms		А	
	-lc					
	- C pulse	1ms				
Collector power dissipation	Pc	1 device		390	W	
Junction temperature	Tj			175		
Operating junction temperature (under switching condition	s) Tjop			150	°C	
Case temperature	Tc			125	C	
Storage temperature	Tstg					
Isolation voltage between terminal and copper base (*1	) Viso	AC : 1min.		2500	VAC	
Scrow torque Mounting (*2)	-			5.0	Nm	
Screw torque Terminals (*3)	-			5.0	IN []]	

Note \*1: All terminals should be connected together when isolation test will be done. Note \*2: Recommendable Value : 3.0-5.0 Nm (M5 or M6) Note \*3: Recommendable Value : 2.5-3.5 Nm (M5)

#### • Electrical characteristics (at Ti= 25°C unless otherwise specified)

láo ma	Symbole	Conditions			Characteristics		Unite
Items	Symbols	Conditions		min.	typ.	max.	Units
Zero gate voltage collector current	Ices	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 1200V		-	-	1.0	mA
Gate-Emitter leakage current	IGES	$V_{CE} = 0V, V_{GE} = \pm 20V$		-	-	200	nA
Gate-Emitter threshold voltage	VGE (th)	V <sub>CE</sub> = 20V, I <sub>C</sub> = 72mA		6.0	6.5	7.0	V
Collector-Emitter saturation voltage	V <sub>CE (sat)</sub>	V <sub>GE</sub> = 15V I <sub>c</sub> = 75A	Tj=25°C	-	1.95	2.40	V
	(terminal)		Tj=125°C	-	2.30	-	
	(terminal)		Tj=150°C		2.35		
	V <sub>CE (sat)</sub>	V <sub>GE</sub> = 15V Ic = 75A	Tj=25°C	-	1.85	2.30	
	(chip)		Tj=125°C	-	2.20	-	
	(criip)	IC - 75A	Tj=150°C		2.25		
Internal gate resistance	R <sub>G</sub> (int)	-		-	10	-	Ω
Input capacitance	Cies	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0V, f = 1MHz		-	6.0	-	nF
Turn-on time	ton			-	600	-	nsec
	tr			-	200	-	
	<b>t</b> r (i)			-	50	-	
Turn-off time	toff			-	600	-	
	tr			-	40	-	
Forward on voltage	VF	$V_{GE} = 0V$	Tj=25°C	-	1.80	2.25	
	(terminal)	v <sub>GE</sub> = 0v I <sub>F</sub> = 75A	Tj=125°C	-	1.95	-	V
	(terminal)		Tj=150°C		1.90		
	VF	V <sub>GE</sub> = 0V I <sub>F</sub> = 75A	Tj=25°C	-	1.70	2.15	
			Tj=125°C	-	1.85	-	
	(chip)		Tj=150°C		1.80		
Reverse recovery time	trr	I⊧ = 75A		-	150	-	nsec

#### Thermal resistance characteristics

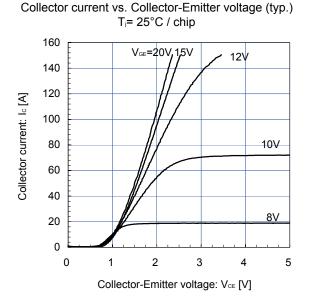
Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	Units
Thermal resistance (1device)	Rth(j-c)	IGBT	-	-	0.38	°C/W
		FWD	-	-	0.58	
Contact thermal resistance (1device) (*4)	Rth(c-f)	with Thermal Compound	-	0.050	-	

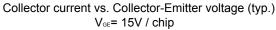
Note \*4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

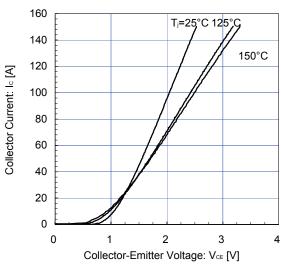


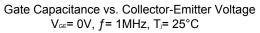
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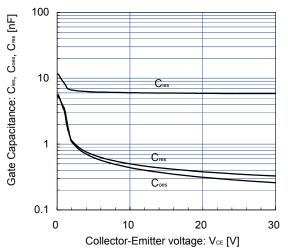
# Characteristics (Representative)

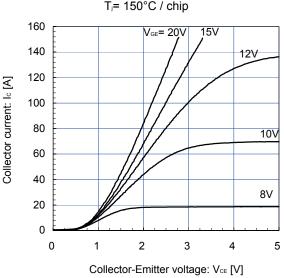




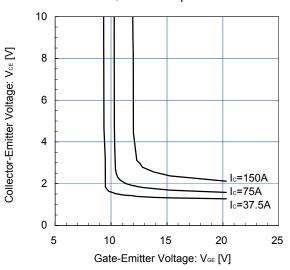


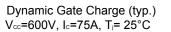


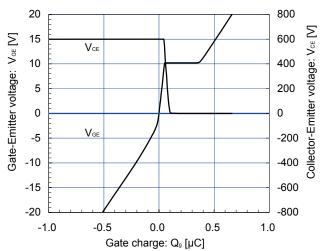


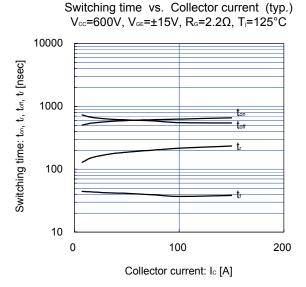


Collector-Emitter voltage vs. Gate-Emitter voltage T<sub>j</sub>= 25°C / chip

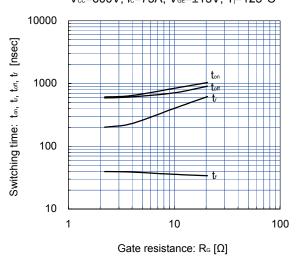




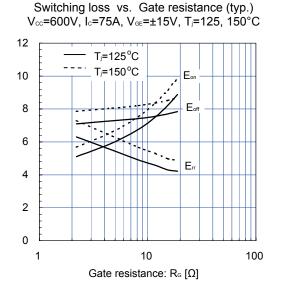


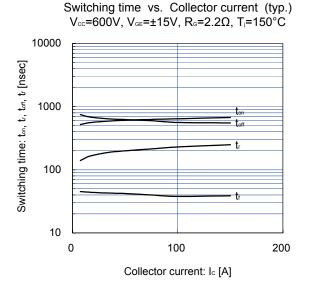


Switching time vs. Gate resistance (typ.)  $V_{cc}$ =600V,  $I_c$ =75A,  $V_{GE}$ =±15V,  $T_j$ =125°C

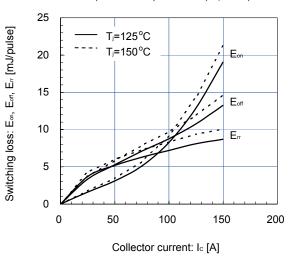


Switching loss: Eon, Eoff, Err [mJ/pulse]

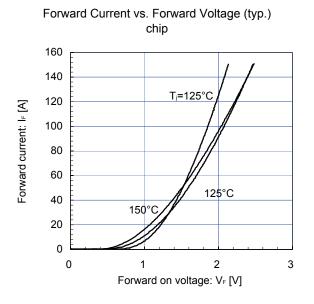




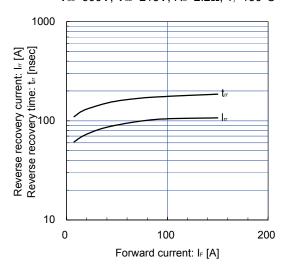
Switching loss vs. Collector current (typ.)  $V_{cc}$ =600V,  $V_{ce}$ =±15V,  $R_{c}$ =2.2 $\Omega$ ,  $T_{j}$ =125, 150°C

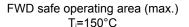


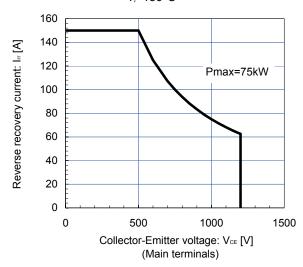
Reverse bias safe operating area (max.) +V<sub>GE</sub>=15V, -V<sub>GE</sub>=15V, R<sub>G</sub>=2.2Ω, T<sub>J</sub>=150°C 160 140 120 Collector current: Ic [A] 100 80 60 40 20 0 400 800 0 1200 1600 Collector-Emitter voltage: VCE [V] (Main terminals)

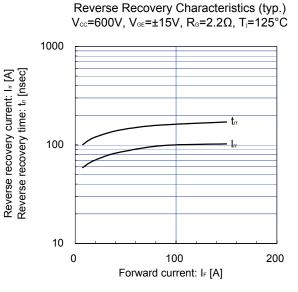


Reverse Recovery Characteristics (typ.)  $V_{cc}$ =600V,  $V_{GE}$ =±15V,  $R_G$ =2.2 $\Omega$ ,  $T_J$ =150°C

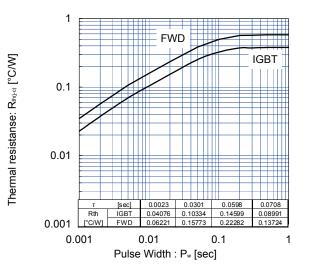








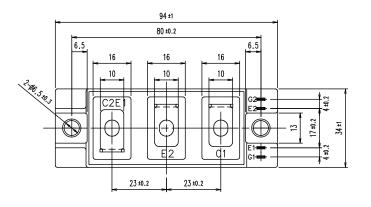
Transient Thermal Resistance (max.)

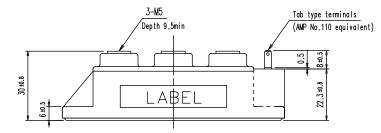




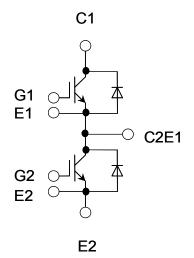
http://www.fujielectric.com/products/semiconductor/

## Outline Drawings, mm





Equivalent Circuit Schematic



http://www.fujielectric.com/products/semiconductor/

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